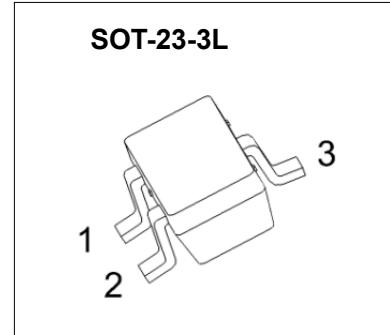


# SOT-23-3L Plastic-Encapsulate MOSFETS

## **CJK3401AH** P-Channel Enhancement Mode Field Effect Transistor

<b>V<sub>(BR)DSS</sub></b>	<b>R<sub>DS(on)</sub>MAX</b>	<b>I<sub>D</sub></b>
-30V	50 mΩ@-10V	-4.2A
	60 mΩ@-4.5V	
	85 mΩ@-2.5V	



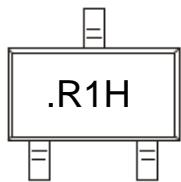
### FEATURE

- High dense cell design for extremely low R<sub>DS(ON)</sub>
- Exceptional on-resistance and maximum DC current capability

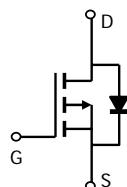
### APPLICATION

- Load Switch for Portable Devices
- DC/DC Converter

### MARKING



### Equivalent Circuit



Solid dot = Green molding compound device,  
if none, the normal device.

### Maximum ratings ( T<sub>a</sub>=25°C unless otherwise noted)

Parameter	Symbol	Value	Unit
Drain-Source Voltage	V <sub>DS</sub>	-30	V
Gate-Source Voltage	V <sub>GS</sub>	±12	V
Continuous Drain Current	I <sub>D</sub>	-4.2	A
Drain Current-Pulsed (not 1)	I <sub>DM</sub>	-27	A
Power Dissipation	P <sub>D</sub>	450	mW
Thermal Resistance from Junction to Ambient (t<5s)	R <sub>θJA</sub>	313	°C/W
Junction Temperature	T <sub>J</sub>	150	°C
Storage Temperature	T <sub>STG</sub>	-55~+150	°C

## MOSFET ELECTRICAL CHARACTERISTICS

$T_a=25^\circ\text{C}$  unless otherwise specified

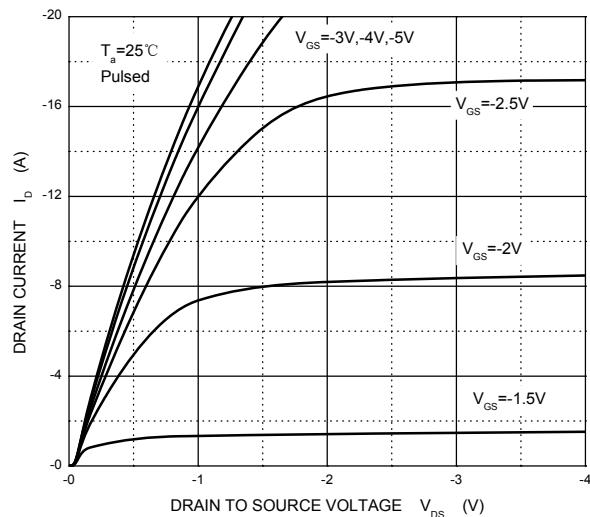
Parameter	Symbol	Test Condition	Min	Typ	Max	Unit
<b>Off characteristics</b>						
Drain-source breakdown voltage	$V_{(\text{BR})\text{DSS}}$	$V_{\text{GS}} = 0\text{V}, I_D = -250\mu\text{A}$	-30			V
Zero gate voltage drain current	$I_{\text{DSS}}$	$V_{\text{DS}} = -24\text{V}, V_{\text{GS}} = 0\text{V}$			-1	$\mu\text{A}$
Gate-source leakage current	$I_{\text{GSS}}$	$V_{\text{GS}} = \pm 12\text{V}, V_{\text{DS}} = 0\text{V}$			$\pm 100$	nA
<b>On characteristics</b>						
Drain-source on-resistance (note 1)	$R_{\text{DS}(\text{on})}$	$V_{\text{GS}} = -10\text{V}, I_D = -4\text{A}$		41	50	$\text{m}\Omega$
		$V_{\text{GS}} = -4.5\text{V}, I_D = -3.5\text{A}$		47	60	$\text{m}\Omega$
		$V_{\text{GS}} = -2.5\text{V}, I_D = -2.5\text{A}$		60	85	$\text{m}\Omega$
Forward transconductance (note 1)	$g_{\text{FS}}$	$V_{\text{DS}} = -5\text{V}, I_D = -5\text{A}$	7			S
Gate threshold voltage	$V_{\text{GS}(\text{th})}$	$V_{\text{DS}} = V_{\text{GS}}, I_D = -250\mu\text{A}$	-0.7		-1.3	V
<b>Dynamic characteristics</b> (note 2)						
Input capacitance	$C_{\text{iss}}$	$V_{\text{DS}} = -15\text{V}, V_{\text{GS}} = 0\text{V}, f = 1\text{MHz}$		1050		pF
Output capacitance	$C_{\text{oss}}$			127		pF
Reverse transfer capacitance	$C_{\text{rss}}$			85		pF
<b>Switching characteristics</b> (note 2)						
Turn-on delay time	$t_{\text{d}(\text{on})}$	$V_{\text{GS}} = -10\text{V}, V_{\text{DS}} = -15\text{V}, R_L = 3.6\Omega, R_{\text{GEN}} = 6\Omega$			6.5	ns
Turn-on rise time	$t_r$				3.5	ns
Turn-off delay time	$t_{\text{d}(\text{off})}$				40	ns
Turn-off fall Time	$t_f$				13	ns
<b>Drain-source diode characteristics and maximum ratings</b>						
Diode forward voltage (note 1)	$V_{\text{SD}}$	$I_S = -1\text{A}, V_{\text{GS}} = 0\text{V}$			-1	V

**Note :**

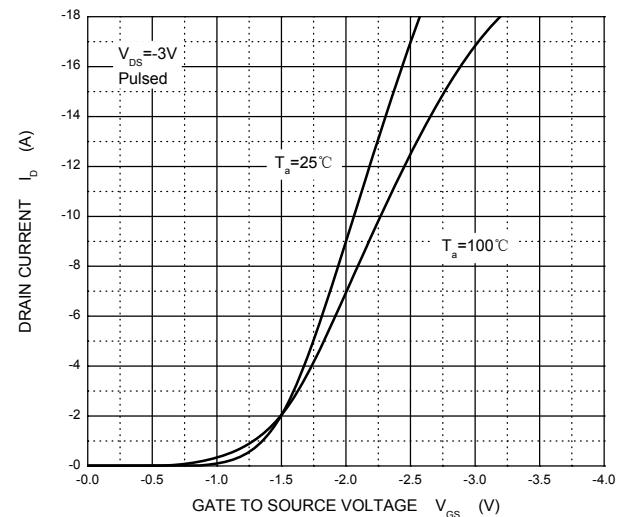
1. Pulse Test : Pulse width  $\leq 300\mu\text{s}$ , duty cycle  $\leq 2\%$ .
2. These parameters have no way to verify.

## Typical Characteristics

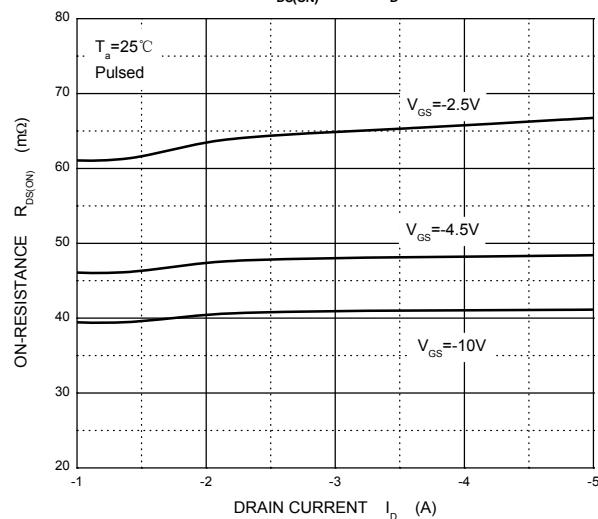
**Output Characteristics**



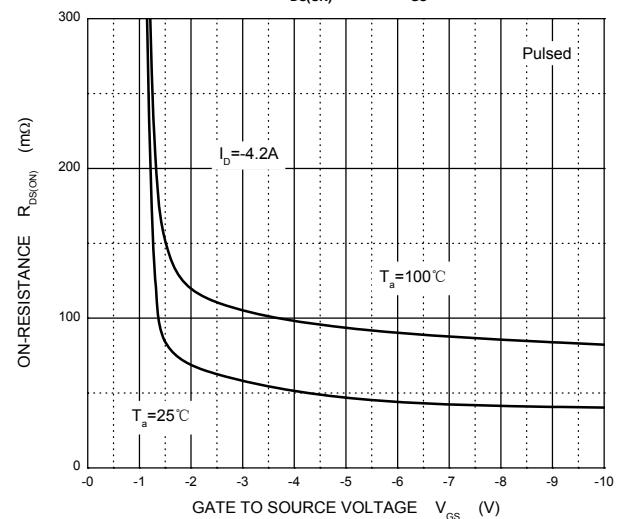
**Transfer Characteristics**



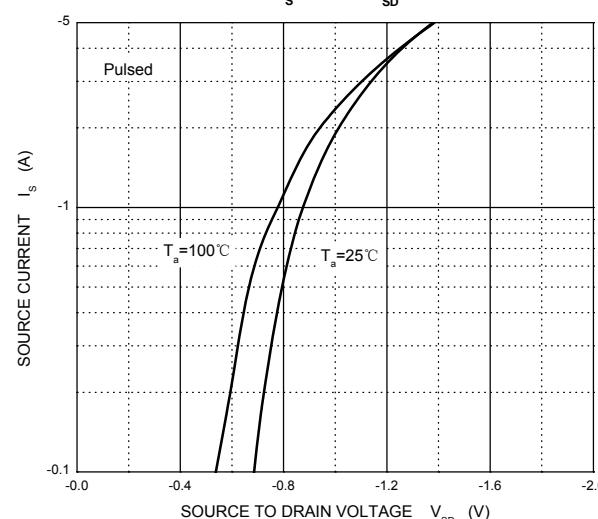
$R_{DS(ON)}$  —  $I_D$



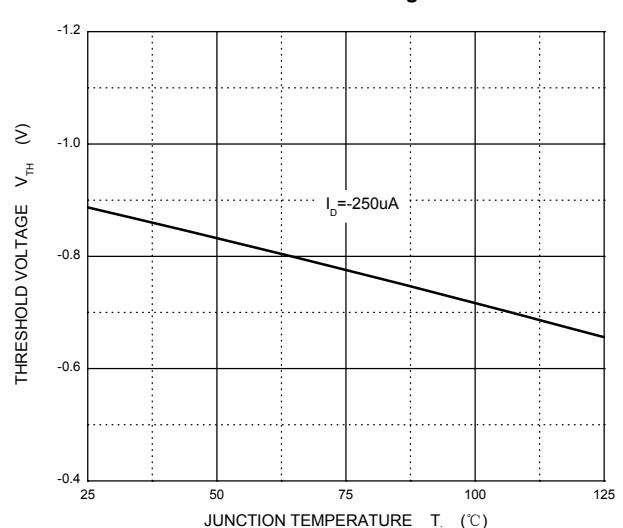
$R_{DS(ON)}$  —  $V_{GS}$



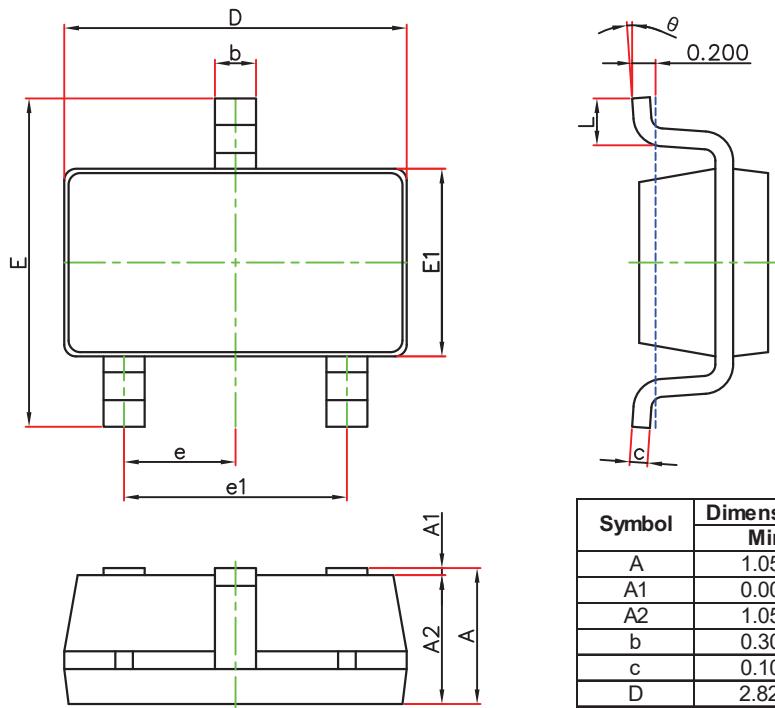
$I_s$  —  $V_{SD}$



**Threshold Voltage**

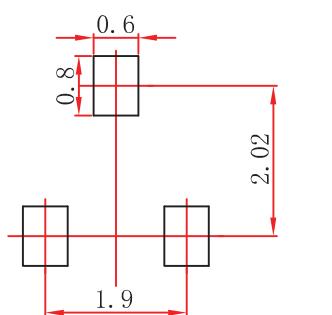


## SOT-23-3L Package Outline Dimensions



Symbol	Dimensions In Millimeters		Dimensions In Inches	
	Min.	Max.	Min.	Max.
A	1.050	1.250	0.041	0.049
A1	0.000	0.100	0.000	0.004
A2	1.050	1.150	0.041	0.045
b	0.300	0.500	0.012	0.020
c	0.100	0.200	0.004	0.008
D	2.820	3.020	0.111	0.119
E1	1.500	1.700	0.059	0.067
E	2.650	2.950	0.104	0.116
e	0.950(BSC)		0.037(BSC)	
e1	1.800	2.000	0.071	0.079
L	0.300	0.600	0.012	0.024
K	0°	8°	0°	8°

## SOT-23-3L Suggested Pad Layout



### Note:

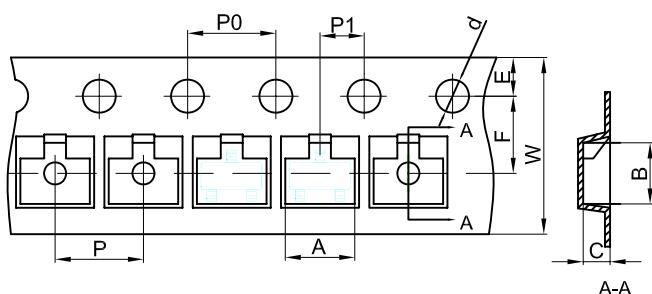
1. Controlling dimension: in millimeters.
2. General tolerance:  $\pm 0.05\text{mm}$ .
3. The pad layout is for reference purposes only.

### NOTICE

JSCJ reserves the right to make modifications,enhancements,improvements,corrections or other changes without further notice to any product herein. JSCJ does not assume any liability arising out of the application or use of any product described herein.

## SOT-23-3L Tape and Reel

### SOT-23-3L Embossed Carrier Tape

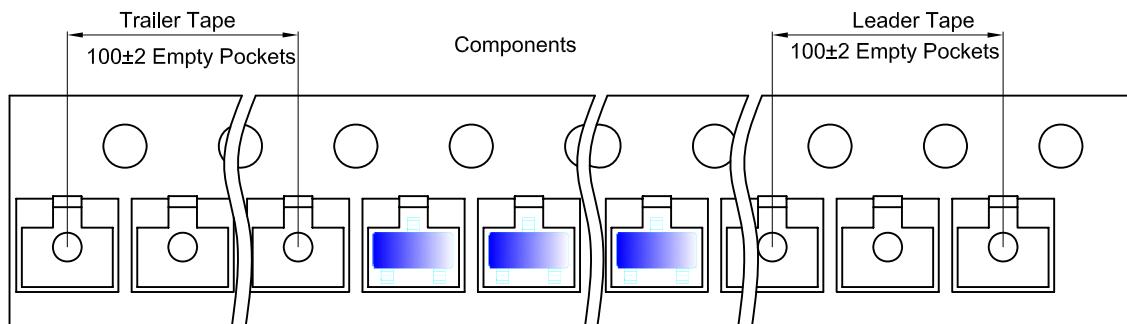


#### Packaging Description:

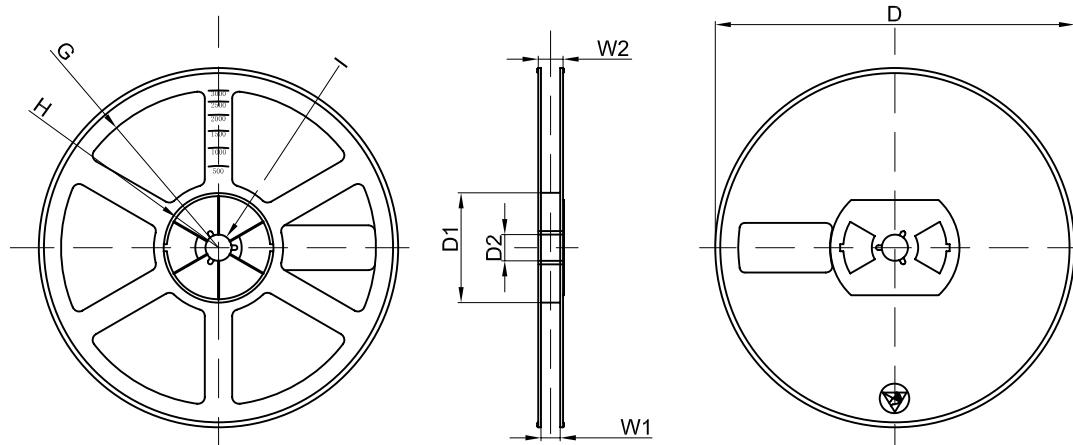
SOT-23-3L parts are shipped in tape. The carrier tape is made from a dissipative (carbon filled) polycarbonate resin. The cover tape is a multilayer film (Heat Activated Adhesive in nature) primarily composed of polyester film, adhesive layer, sealant, and anti-static sprayed agent. These reeled parts in standard option are shipped with 10,000 units per 13" or 33.00 cm diameter reel. The reels are clear in color and is made of polystyrene plastic (anti-static coated).

Dimensions are in millimeter										
Pkg type	A	B	C	d	E	F	P0	P	P1	W
SOT-23-3L	3.15	2.77	1.22	Ø1.50	1.75	3.50	4.00	4.00	2.00	8.00
(Tolerance)	+/-0.1	+/-0.1	+/-0.1	+/-0.1	+/-0.1	+/-0.1	+/-0.1	+/-0.1	+/-0.1	+0.3/-0.1

### SOT-23-3L Tape Leader and Trailer



### SOT-23-3L Reel



Dimensions are in millimeter								
Reel Option	D	D1	D2	G	H	I	W1	W2
7" Dia	Ø178.00	54.40	13.00	R78.00	R25.60	R6.50	9.50	12.30
Tolerance	+/-2	+/-1	+/-1	+/-1	+/-1	+/-1	+/-1	+/-1

REEL	Reel Size	Box	Box Size(mm)	Carton	Carton Size(mm)	G.W.(kg)
3000 pcs	7 inch	30,000 pcs	203×203×195	120,000 pcs	438×438×220	